

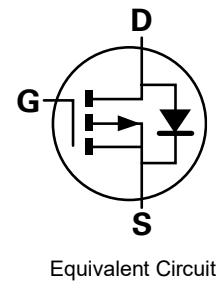
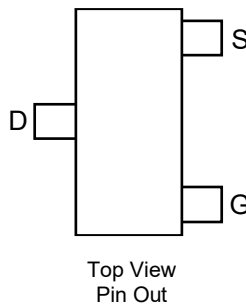
## Product Summary

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
-100V	1.0Ω @ V <sub>GS</sub> = -10V	-0.7A
	1.45Ω @ V <sub>GS</sub> = -6.0V	-0.5A

## Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- DC-DC converters
- Power-management functions
- Disconnect switches
- Motor control



## Features and Benefits

- Fast Switching Speed
- Low Input Capacitance
- Low Gate Charge
- Low Threshold
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The ZXMP10A13FQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

## Mechanical Data

- Package: SOT23
- Package Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208
- Weight: 0.009 grams (Approximate)

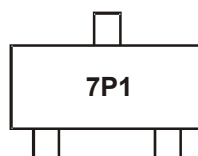
## Ordering Information (Note 4)

Orderable Part Number	Package	Packing	
		Qty.	Carrier
ZXMP10A13FQTA	SOT23 (Type DN)	3000	Tape & Reel
ZXMP10A13FQTC	SOT23 (Type DN)	10000	Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information

SOT23 (Type DN)



7P1 = Product Type Marking Code

**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

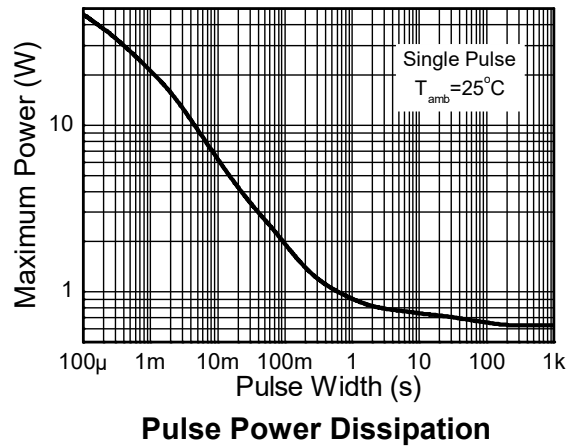
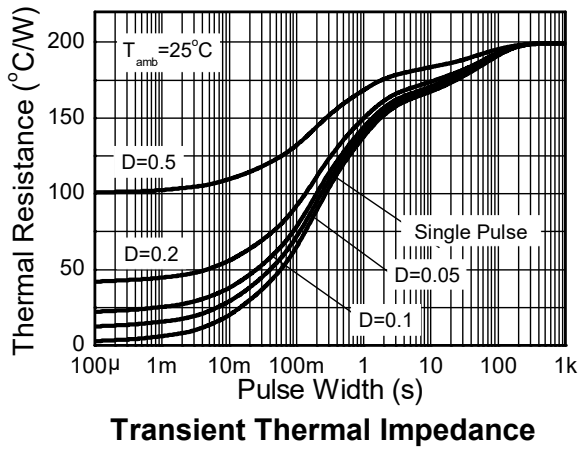
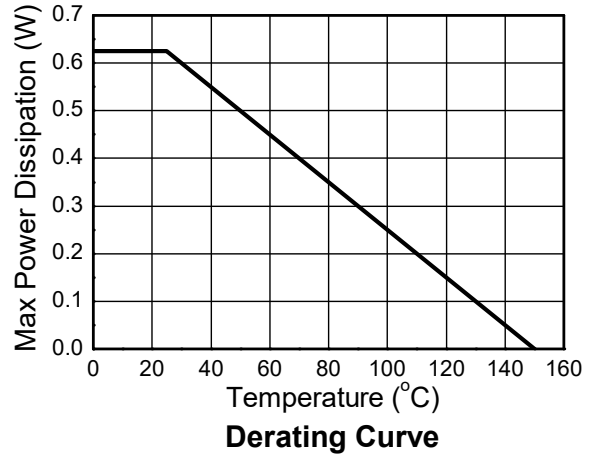
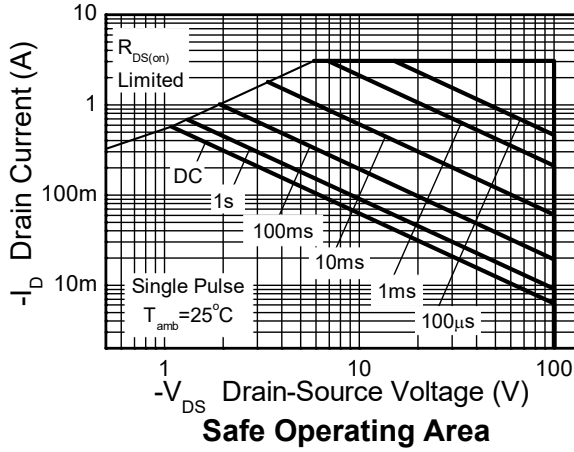
Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V <sub>DSS</sub>	-100	V
Gate-Source Voltage			V <sub>GS</sub>	±20	V
Continuous Drain Current	V <sub>GS</sub> = -10V	T <sub>A</sub> = +70°C (Note 6)	I <sub>D</sub>	-0.7	A
		(Note 6)		-0.5	
		(Note 6)		-0.6	
Pulsed Drain Current (Note 7)			I <sub>DM</sub>	-3.1	A
Continuous Source Current (Body Diode) (Note 5)			I <sub>S</sub>	-1.1	A
Pulsed Source Current (Body Diode) (Note 7)			I <sub>SM</sub>	-3.1	A

**Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Power Dissipation (Note 5)		P <sub>D</sub>	625	mW
Linear Derating Factor			5	mW/°C
Power Dissipation (Note 6)		P <sub>D</sub>	806	mW
Linear Derating Factor			6.4	mW/°C
Thermal Resistance, Junction to Ambient (Note 5)		R <sub>θJA</sub>	200	°C/W
Thermal Resistance, Junction to Ambient (Note 6)		R <sub>θJA</sub>	155	°C/W
Thermal Resistance, Junction to Leads (Note 8)		R <sub>θJL</sub>	194	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

- Notes:
5. For a device surface mounted on 25mm x 25mm FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions.
  6. For a device surface mounted on FR-4 PCB measured at t ≤ 5 secs.
  7. Repetitive rating 25mm x 25mm FR-4 PCB, D = 0.05 pulse width = 10μs - pulse current limited by maximum junction temperature.
  8. Thermal resistance from junction to solder-point (at the end of the drain lead).

**Thermal Characteristics**

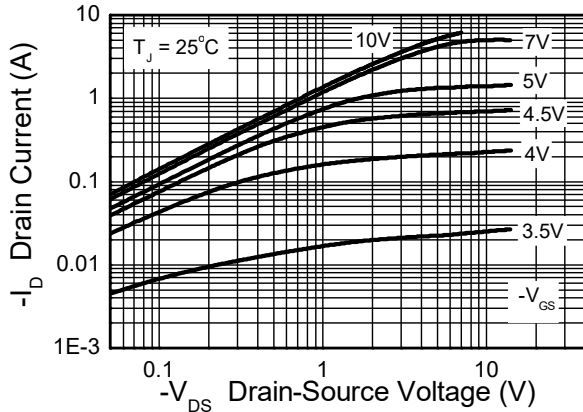


**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

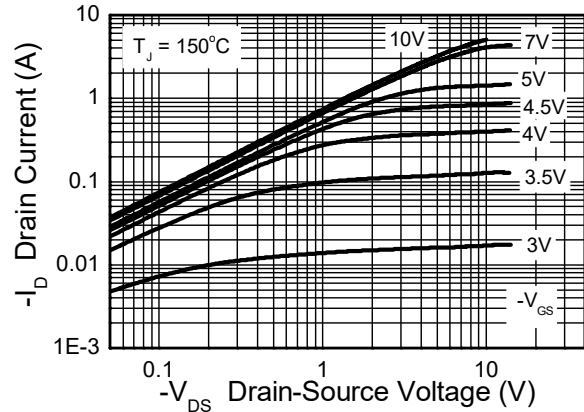
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-100	—	—	V	I <sub>D</sub> = -250μA, V <sub>GS</sub> = 0
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	—	—	-1.0	μA	V <sub>DS</sub> = -100V, V <sub>GS</sub> = 0
Gate-Source Leakage	I <sub>GSS</sub>	—	—	±100	nA	V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-2.0	—	-4.0	V	I <sub>D</sub> = -250μA, V <sub>DS</sub> = V <sub>GS</sub>
Static Drain-Source On-Resistance (Note 9)	R <sub>DS(ON)</sub>	—	—	1.0	Ω	V <sub>GS</sub> = -10V, I <sub>D</sub> = -0.6A
				1.45		V <sub>GS</sub> = -6.0V, I <sub>D</sub> = -0.5A
Forward Transconductance (Notes 9 and 11)	g <sub>fs</sub>	—	1.2	—	S	V <sub>DS</sub> = -15V, I <sub>D</sub> = -0.6A
Diode Forward Voltage (Note 9)	V <sub>SD</sub>	—	-0.85	-0.95	V	T <sub>J</sub> = +25°C, I <sub>S</sub> = -0.75A, V <sub>GS</sub> = 0
Reverse-Recovery Time (Note 11)	t <sub>RR</sub>	—	29	—	ns	T <sub>J</sub> = +25°C, I <sub>F</sub> = -0.9A,
Reverse-Recovery Charge (Note 11)	Q <sub>RR</sub>	—	31	—	nC	di/dt = 100A/μs
<b>DYNAMIC CHARACTERISTICS</b> (Note 11)						
Input Capacitance	C <sub>iss</sub>	—	141	—	pF	V <sub>DS</sub> = -50V, V <sub>GS</sub> = 0 f = 1.0MHz
Output Capacitance	C <sub>oss</sub>	—	13.1	—		
Reverse Transfer Capacitance	C <sub>rss</sub>	—	10.8	—		
Turn-On Delay Time (Note 10)	t <sub>D(ON)</sub>	—	1.6	—	ns	V <sub>DD</sub> = -50V, I <sub>D</sub> = -1.0A, R <sub>G</sub> ≈ 6.0Ω, V <sub>GS</sub> = -10V
Turn-On Rise Time (Note 10)	t <sub>R</sub>	—	2.1	—		
Turn-Off Delay Time (Note 10)	t <sub>D(OFF)</sub>	—	5.9	—		
Turn-Off Fall Time (Note 10)	t <sub>F</sub>	—	3.3	—		
Total Gate Charge (Note 10)	Q <sub>g</sub>	—	1.8	—	nC	V <sub>DS</sub> = -50V, V <sub>GS</sub> = -5.0V, I <sub>D</sub> = -0.6A
Total Gate Charge (Note 10)	Q <sub>g</sub>	—	3.5	—	nC	V <sub>DS</sub> = -50V, V <sub>GS</sub> = -10V, I <sub>D</sub> = -0.6A
Gate-Source Charge (Note 10)	Q <sub>gs</sub>	—	0.6	—		
Gate-Drain Charge (Note 10)	Q <sub>gd</sub>	—	1.6	—		

- Notes: 9. Measured under pulsed conditions. Pulse width = 300μs. Duty cycle ≤ 2%.  
10. Switching characteristics are independent of operating junction temperature.  
11. For design aid only, not subject to production testing.

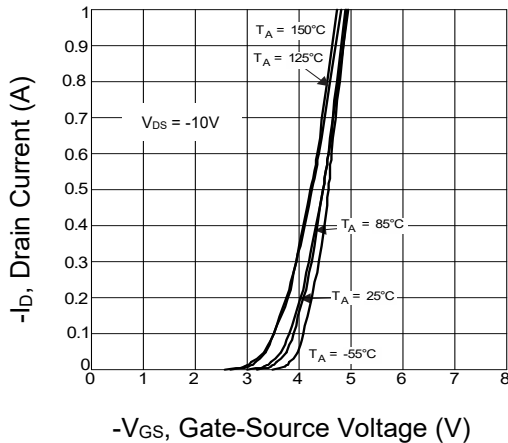
**Typical Characteristics**



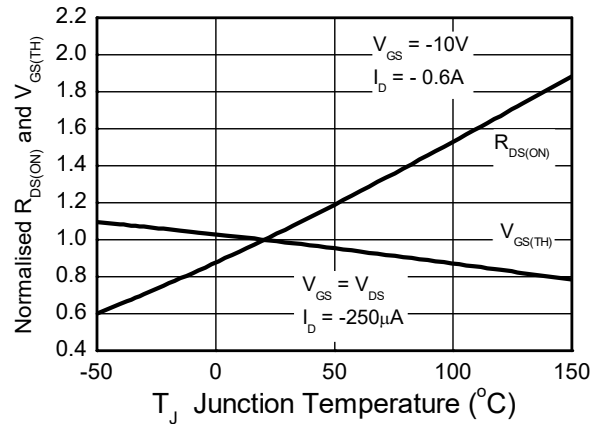
**Output Characteristics**



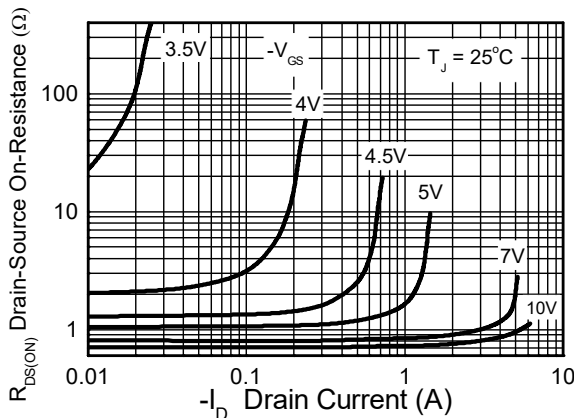
**Output Characteristics**



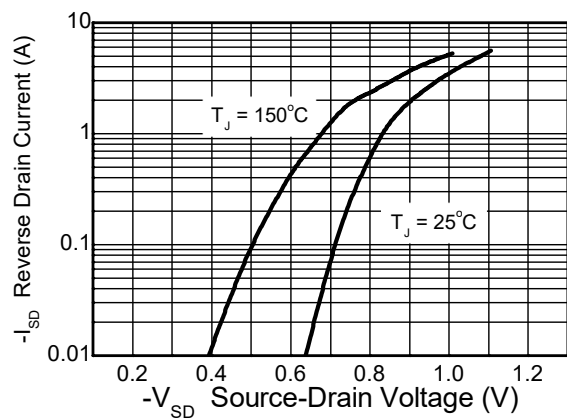
**Typical Transfer Characteristics**



**Normalised Curves v Temperature**

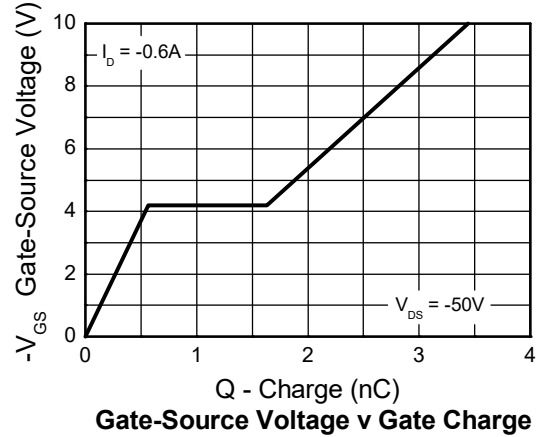
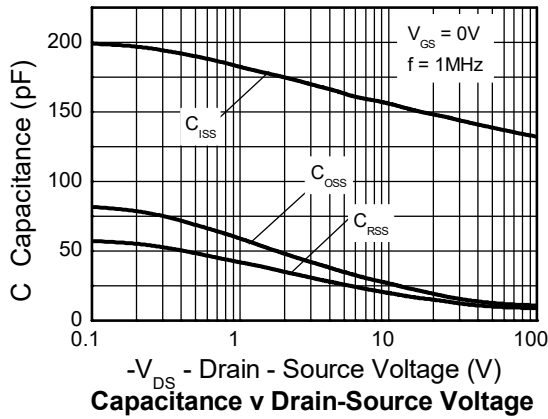


**On-Resistance v Drain Current**

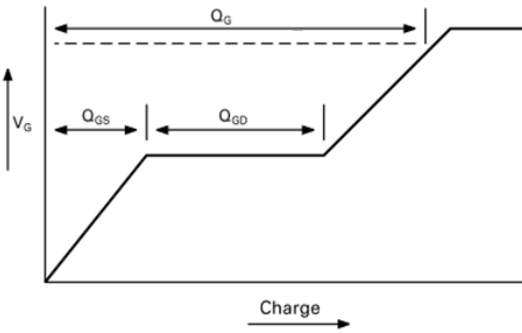


**Source-Drain Diode Forward Voltage**

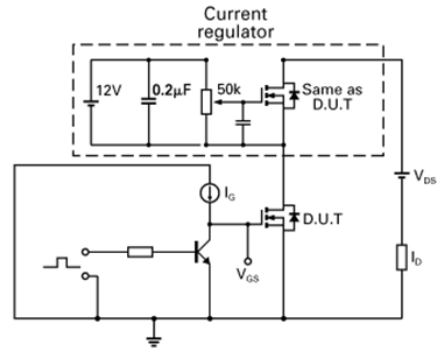
**Typical Characteristics** (continued)



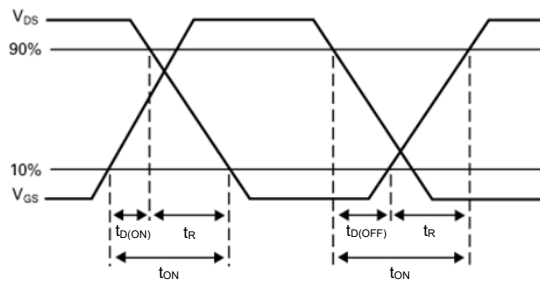
**Test Circuits**



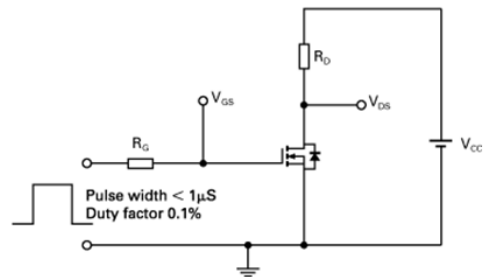
Basic Gate Charge Waveform



Gate Charge Test Circuit



Switching Time Waveforms

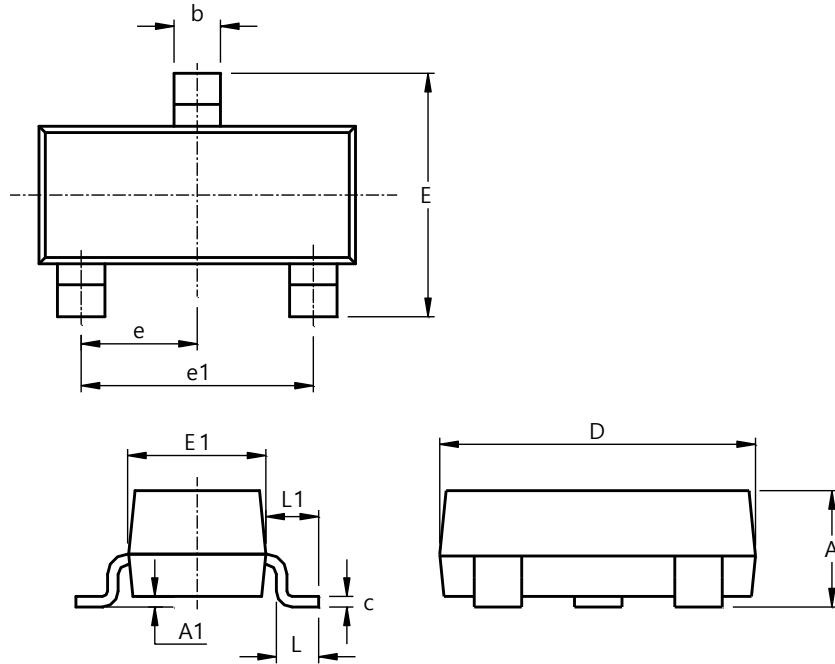


Switching Time Test Circuit

**Package Outline Dimensions**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT23 (Type DN)**

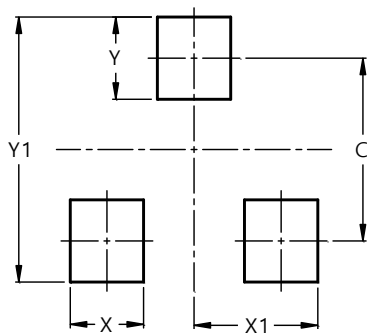


SOT23 Type DN			
Dim	Min	Max	Typ
A	0.89	1.12	1.00
A1	0.01	0.10	0.05
b	0.30	0.51	0.45
c	0.08	0.20	0.10
D	2.80	3.04	3.00
E	2.10	2.64	2.42
E1	1.20	1.40	1.37
e	0.95 REF		
e1	1.90 REF		
L	0.25	0.60	0.30
L1	0.45	0.62	0.54
All Dimensions in mm			

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT23 (Type DN)**



Dimensions	Value (in mm)
C	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9

**IMPORTANT NOTICE**

1. DIODES INCORPORATED (Diodes) AND ITS SUBSIDIARIES MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).
2. The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes' products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes' products. Diodes' products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of Diodes' products for their intended applications, (c) ensuring their applications, which incorporate Diodes' products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.
3. Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and liabilities.
4. Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.
5. Diodes' products are provided subject to Diodes' Standard Terms and Conditions of Sale (<https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/>) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.
6. Diodes' products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes' products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.
7. While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.
8. Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.
9. This Notice may be periodically updated with the most recent version available at <https://www.diodes.com/about/company/terms-and-conditions/important-notice>

The Diodes logo is a registered trademark of Diodes Incorporated in the United States and other countries.  
All other trademarks are the property of their respective owners.  
© 2026 Diodes Incorporated. All Rights Reserved.

[www.diodes.com](http://www.diodes.com)